

Supplementary Information

Battery-Like Supercapacitors from Diamond Networks and Water-Soluble Redox Electrolytes

Siyu Yu,^a Nianjun Yang,*^a Hao Zhuang,^a Soumen Mandal,^b Oliver A. Williams,^b Bing Yang,^c
Nan Huang,^c Xin Jiang*^a

^a Institute of Materials Engineering, University of Siegen, 57076 Siegen, Germany

^b School of Physics and Astronomy, Cardiff University, Cardiff CF24 3AA, UK

^c Shenyang National Laboratory for Materials Science, Institute of Metal Research (IMR),
Chinese Academy of Sciences (CAS), No.72 Wenhua Road, Shenyang 110016 China

E-mail: nianjun.yang@uni-siegen.de; xin.jiang@uni-siegen.de

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Table S1. Capacitance comparison of diamond nanostructures based electric double layer capacitors (EDLCs) and pseudocapacitors (PCs).

Type	Capacitor Electrode	Capacitance [mF cm ⁻²]	Electrolyte	Ref.
EDLC	Diamond	(4 – 7)×10 ⁻³	Na ₂ SO ₄	1
	Diamond network	3.53	Na ₂ SO ₄	This work
	Diamond/Silicon nanowires	0.1	PMPyrrTFSI + propylene carbonate	2
		1.5	Et ₃ NH TFSI	3
	Diamond foam	0.60	NaClO ₄	4
		0.44	PMPyrrTFSI + propylene carbonate	4
		1.97	H ₂ SO ₄	5
	Honeycomb diamond	3.91	H ₂ SO ₄	6
		0.67	TEABF ₄ + propylene carbonate	7
	Porous diamond	3	LiClO ₄	8
	BDD/TiO ₂	7.46	NaNO ₃	9-11
	TiO ₂ /BDD/Ta	5.23	Na ₂ SO ₄	12
	BDD/Nanotube	0.58	PBS	13
PC	Diamond	41.51	Na ₂ SO ₄ + Fe(CN) ₆ ^{3-/4-}	This work
	Diamond network	73.42	Na ₂ SO ₄ + Fe(CN) ₆ ^{3-/4-}	This work
	MnO ₂ /Diamond	7.82	Na ₂ SO ₄	1
	Ni(OH) ₂ /Diamond Nanowire	91	NaOH	14

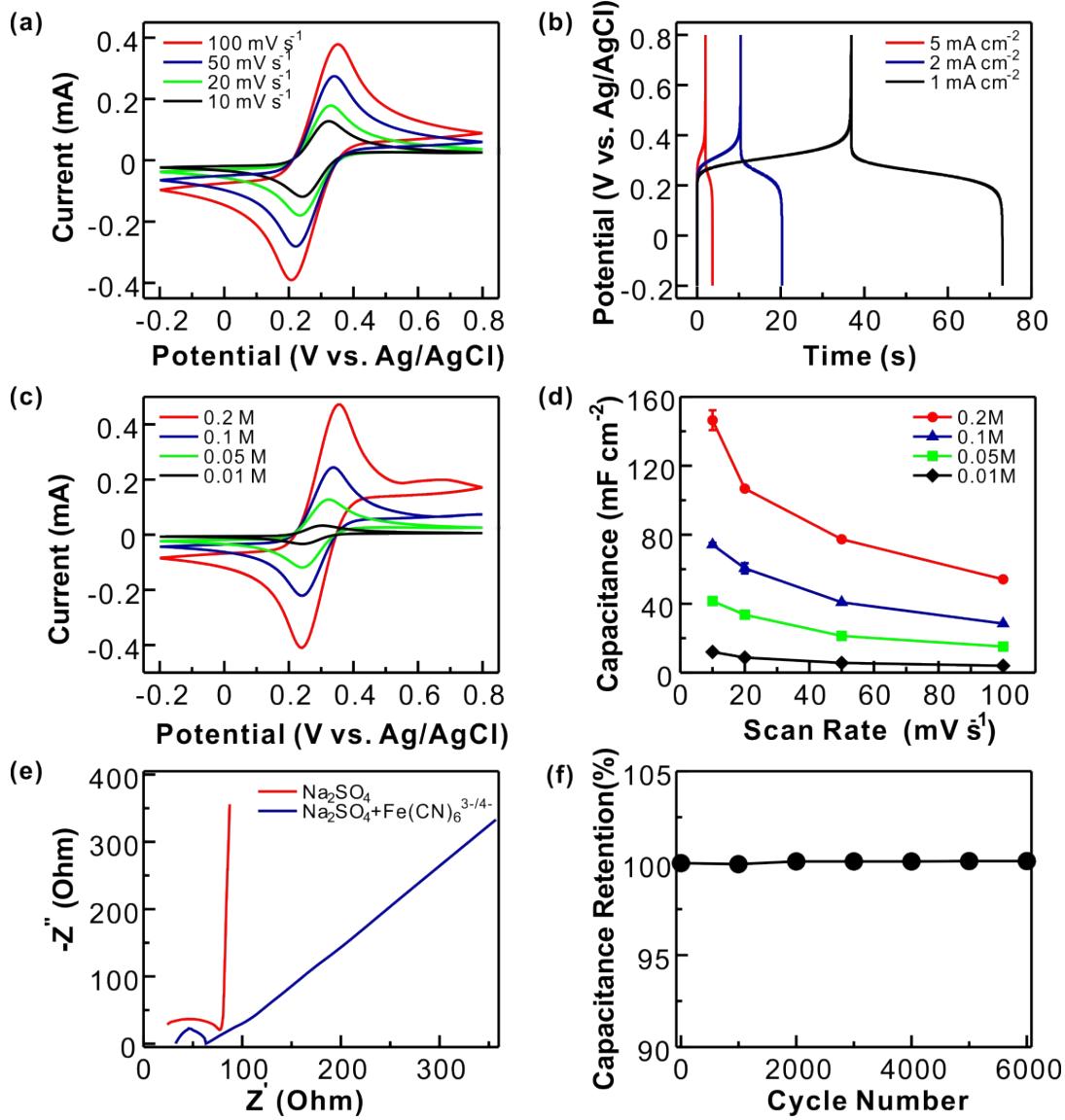


Figure S1. Performance of a diamond PC using $\text{Fe}(\text{CN})_6^{3-/4-}$ redox electrolytes. (a) Cyclic voltammograms of 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 at the scan rates of 10, 20, 50, and 100 mV s⁻¹. (b) Charge/discharge curves of 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 at the current densities of 1.0, 2.0, and 5.0 mA cm⁻². (c) Cyclic voltammograms of $\text{Fe}(\text{CN})_6^{3-/4-}$ with the concentrations of 0.01, 0.05, 0.1, and 0.2 M in 1.0 M Na_2SO_4 at the scan rate of 10 mV s⁻¹. (d) Capacitance comparison calculated from cyclic voltammogramms at different scan rates and different concentrations of $\text{Fe}(\text{CN})_6^{3-/4-}$. (e) Nyquist plots in the frequency range of 10⁶ - 0.01 Hz with and without 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 as the electrolyte. (f) Capacitance

retention at a charge/discharge current density of 5 mA cm⁻² in 0.05 M Fe(CN)₆^{3-/4-} + 1.0 M Na₂SO₄.

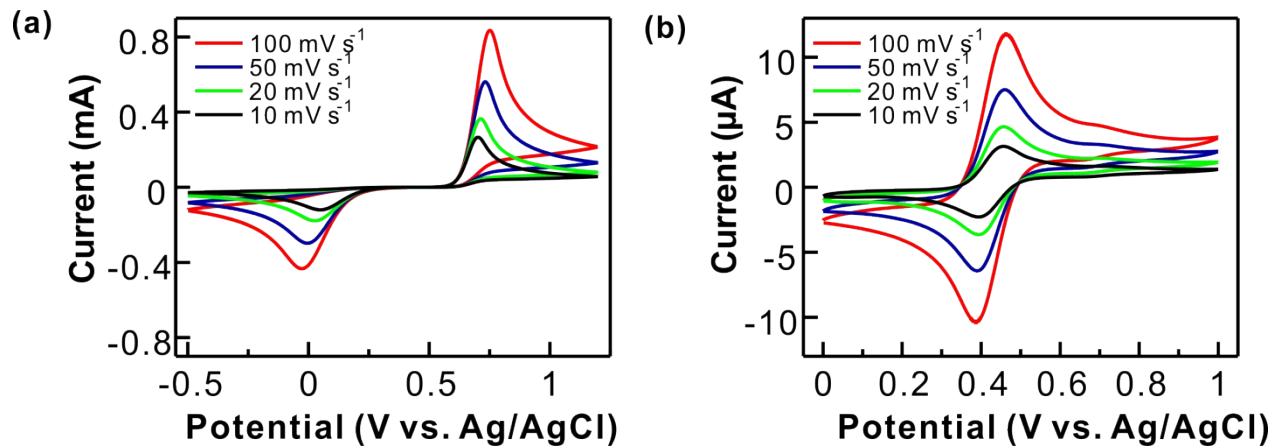


Figure S2. Performance of a diamond PC using other water-soluble redox electrolytes. (a) Cyclic voltammograms of 0.1 M hydroquinone in 1.0 M H₂SO₄. (b) Cyclic voltammograms of 2 mM FcTMAPF₆ in 0.1 KCl. The scan rates were 10, 20, 50, and 100 mV s⁻¹.

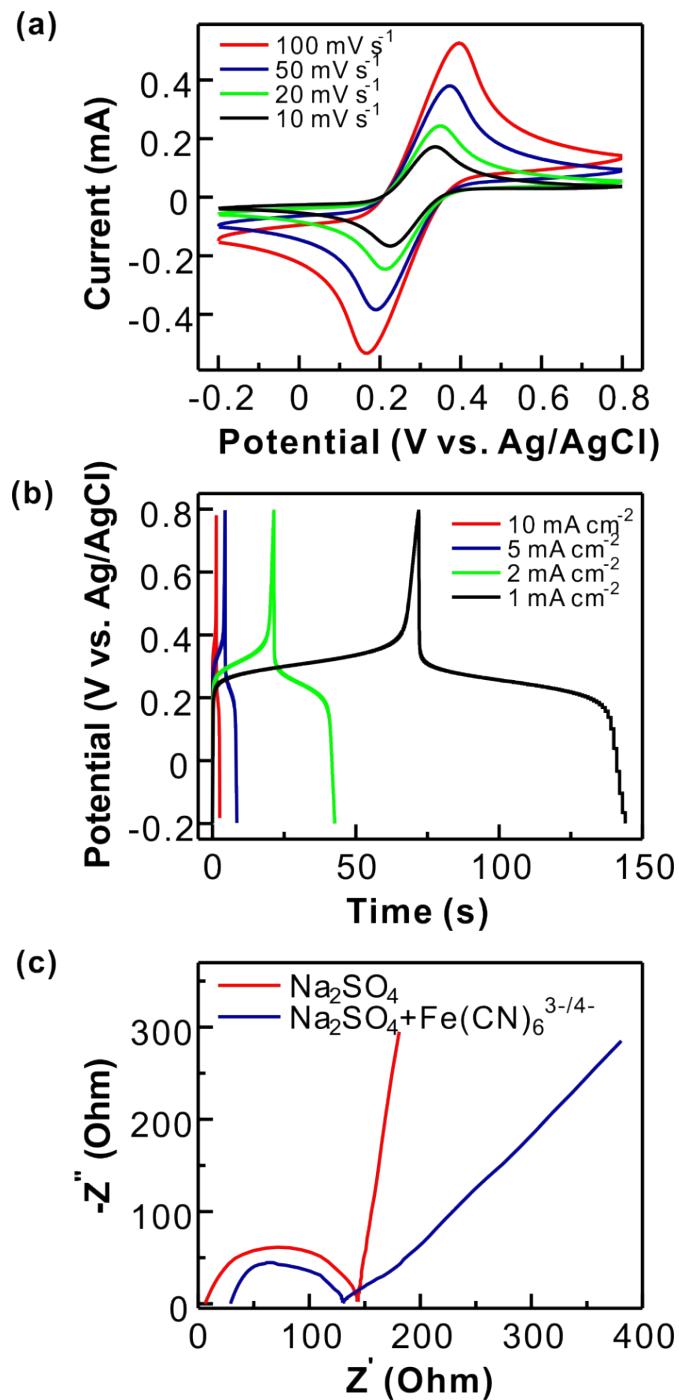


Figure S3. Performance of a diamond network PC using water-soluble redox electrolytes. (a) Cyclic voltammograms of 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 at the scan rates of 10, 20, 50, and 100 mV s⁻¹. (b) Charge/discharge curves of 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 at current densities of 1.0, 2.0, and 5.0 mA cm⁻². (c) Nyquist plots in the frequency range of 10⁶ - 0.01 Hz with and without 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ in 1.0 M Na_2SO_4 as the electrolyte.

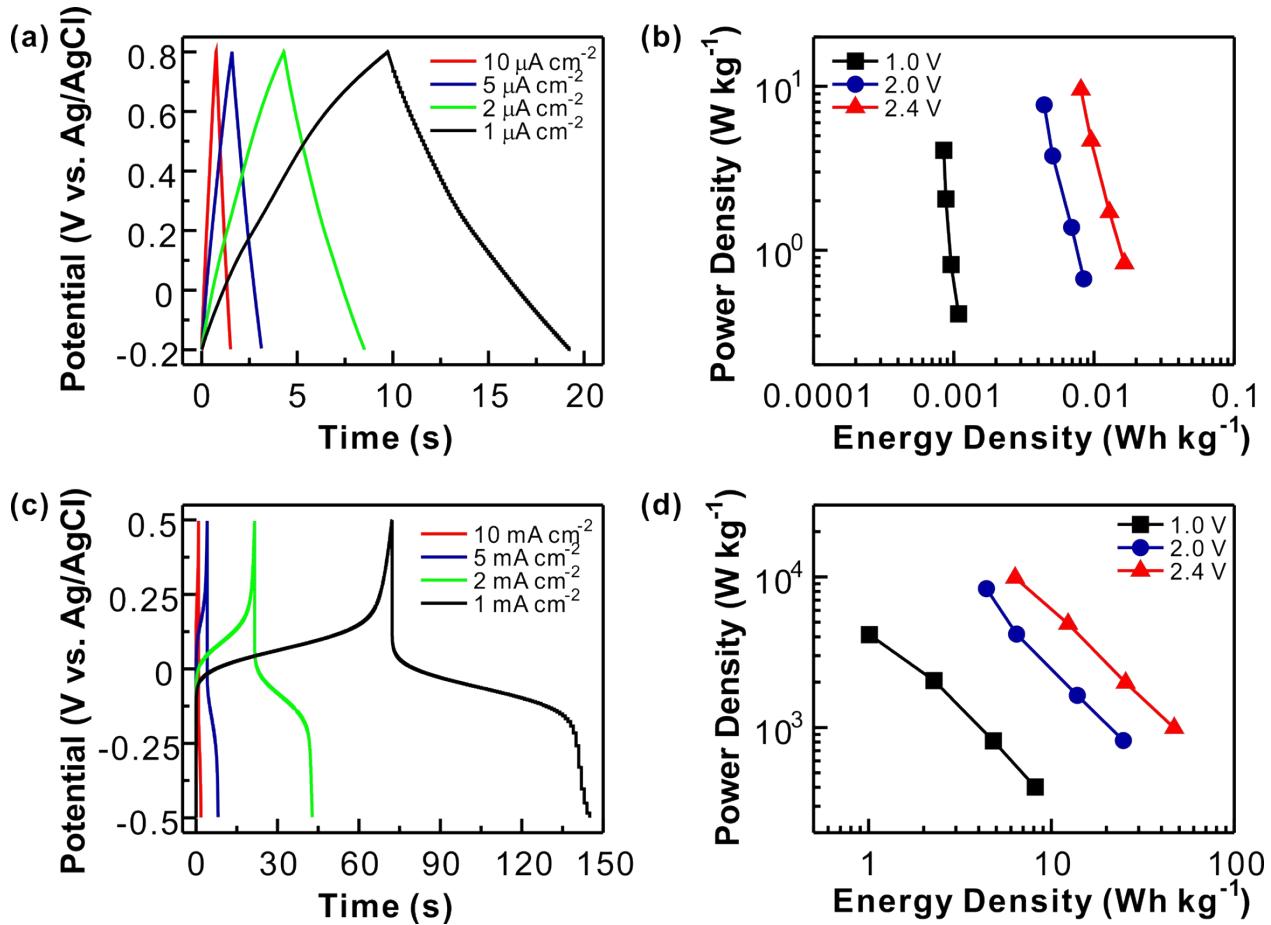


Figure S4. Performance of diamond symmetric EDLC and PC devices. (a) Charge/discharge curves of a diamond EDLC device in 1.0 M Na_2SO_4 at the current density of 1.0, 2.0, 5.0 and 10.0 $\mu\text{A cm}^{-2}$. (b) Ragone plots of a diamond EDLC device in 1.0 M Na_2SO_4 with a cell voltage of 1.0, 2.0 and 2.4 V. (c) Charge/discharge curves of a diamond PC device in 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ + 1.0 M Na_2SO_4 at the current density of 1.0, 2.0, 5.0 and 10.0 mA cm^{-2} . (d) Ragone plots of a diamond PC device in 0.05 M $\text{Fe}(\text{CN})_6^{3-/4-}$ + 1.0 M Na_2SO_4 with a cell voltage of 1.0, 2.0 and 2.4 V.

1. S. Yu, N. Yang, H. Zhuang, J. Meyer, S. Mandal, O. A. Williams, I. Lilge, H. Schönherr and X. Jiang, *The Journal of Physical Chemistry C*, 2015, **119**, 18918-18926.
2. F. Gao, G. Lewes-Malandrakis, M. T. Wolfer, W. Müller-Sebert, P. Gentile, D. Aradilla, T. Schubert and C. E. Nebel, *Diamond Relat. Mater.*, 2015, **51**, 1-6.
3. D. Aradilla, F. Gao, G. Lewes-Malandrakis, W. Müller-Sebert, D. Gaboriau, P. Gentile, B. Iliev, T. Schubert, S. Sadki, G. Bidan and C. E. Nebel, *Electrochemistry Communications*, 2016, **63**, 34-38.
4. F. Gao, M. T. Wolfer and C. E. Nebel, *Carbon*, 2014, **80**, 833-840.
5. K. Honda, T. N. Rao, D. A. Tryk, A. Fujishima, M. Watanabe, K. Yasui and H. Masuda, *J. Electrochem. Soc.*, 2000, **147**, 659-664.
6. K. Honda, T. N. Rao, D. A. Tryk, A. Fujishima, M. Watanabe, K. Yasui and H. Masuda, *J. Electrochem. Soc.*, 2001, **148**, A668-A679.
7. M. Yoshimura, K. Honda, R. Uchikado, T. Kondo, T. N. Rao, D. A. Tryk, A. Fujishima, Y. Sakamoto, K. Yasui and H. Masuda, *Diamond Relat. Mater.*, 2001, **10**, 620-626.
8. C. Hébert, E. Scorsone, M. Mermoux and P. Bergonzo, *Carbon*, 2015, **90**, 102-109.
9. K. Siuzdak, R. Bogdanowicz, M. Sawczak and M. Sobaszek, *Nanoscale*, 2015, **7**, 551-558.
10. M. Sobaszek, K. Siuzdak, M. Sawczak, J. Ryl and R. Bogdanowicz, *Thin Solid Films*, 2016, **601**, 35-40.
11. M. Sawczak, M. Sobaszek, K. Siuzdak, J. Ryl, R. Bogdanowicz, K. Darowicki, M. Gazda and A. Cenian, *Journal of The Electrochemical Society*, 2015, **162**, A2085-A2092.
12. C. Shi, H. Li, C. Li, M. Li, C. Qu and B. Yang, *Applied Surface Science*, 2015, **357, Part B**, 1380-1387.
13. C. Hébert, J. P. Mazellier, E. Scorsone, M. Mermoux and P. Bergonzo, *Carbon*, 2014, **71**, 27-33.
14. F. Gao and C. E. Nebel, *physica status solidi (a)*, 2015, **212**, 2533-2538.